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1. Introduction

Three-dimensional (3D) organic–inorganic metal halide hybrid perovskites are promising photovoltaic materials due to their unique optoelectronic properties.¹⁻¹¹ A state-of-the-art perovskite solar cell (PSC) has been certified to exhibit an astonishing power conversion efficiency (PCE) of 25.5%.¹² However, 3D perovskites are quite sensitive to moisture and oxygen, resulting in significant degradation in ambient atmospheres. Thus, the long-term stability of PSCs by 3D perovskites is a major bottleneck for their practical applications.^{13,14} In comparison with 3D perovskites, two-dimensional (2D) perovskites have been developed to create stable PSCs.¹⁵ Studies have indicated that the utilization of a small amount of large organic cations to replace regular smaller cations in the perovskite precursors to form a 2D perovskite passivation layer on the top of a 3D perovskite is a facile way to boost both the efficiency and

Tao Zhu,^a Lening Shen,^a Hanlin Chen,^a Yongrui Yang,^a Luyao Zheng,^a Rui Chen, ^b^a Jie Zheng, ^b Junpeng Wang ^{*} and Xiong Gong ^{*}

Conjugated molecules have been typically utilized as either hole or electron extraction layers to boost the device performance of perovskite solar cells (PSCs), formed from three-dimensional (3D) perovskites, due to their high charge carrier mobility and electrical conductivity. However, the passivating role of conjugated molecules in creating two-dimensional (2D) perovskites has rarely been reported. In this study, we report novel conjugated aniline 3-phenyl-2-propen-1-amine (PPA) based 2D perovskites and further demonstrate efficient and stable PSCs containing a (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film (where MA is $CH_3NH_3^+$). The (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film possesses superior crystallinity and passivated trap states, resulting in enhanced charge transport and suppressed charge carrier recombination compared to those of a 3D MAPbI₃ thin film. As a result, PSCs containing the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film exhibit a power conversion efficiency (PCE) of 21.98%, which is approximately a 25% enhancement compared to that of the MAPbl₃ thin film. Moreover, unencapsulated PSCs containing the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film retain 50% of their initial PCE after 1200 hours in an ambient atmosphere (25 $^\circ$ C, and 30 \pm 10 humidity), whereas PSCs with the 3D MAPbl₃ thin film show significant degradation after 100 hours and a degradation of more than 50% of their original PCE after 500 hours. These results demonstrate that the incorporation of conjugated molecules as organic spacer cations to create 2D perovskites on top of 3D perovskites is an effective way to approach high-performance PSCs.

stability of PSCs.^{16–21} Using phenethylammonium iodide (PEAI) to treat the surface of a 3D perovskite, You *et al.* found out that PEAI-based 2D perovskites could reduce surface defects and suppress surface non-radiative recombination, resulting in enhanced PCEs.¹⁹ Chen *et al.*²¹ demonstrated that 2-thiophenemethylammonium cations can be successfully embedded into 3D perovskites, resulting in enlarged crystallinity and orientated 2D/3D perovskite bilayer thin films. Recently, we reported novel propargylamine-based quasi-2D perovskite thin films and further demonstrated efficient and stable PSCs with dramatically suppressed photocurrent hysteresis.¹⁵ While impressive device performance has been reported for PSCs with 2D/3D perovskite bilayer thin films, 2D perovskites based on insulating organic molecules possess poor charge transport, restricting the device performance of PSCs.^{22–28}

Conjugated organic molecules have received considerable attention as the hole and/or electron transport layers in PSCs with 3D perovskite thin films due to their high charge carrier mobilities and electrical conductivities compared to those of insulating organic molecules.^{29,30} But the use of conjugated organic molecules to create 2D perovskites has rarely been reported. Hence, it is reasonable to develop conjugated organic molecule-based 2D perovskites for boosting the device performance of PSCs with 2D/3D perovskite bilayer thin films. The

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^aSchool of Polymer Science and Polymer Engineering, The University of Akron, Akron, OH 44325, USA. E-mail: xgong@uakron.edu; jwang6@uakron.edu; Fax: +1 330 9723406

^bDepartment of Chemical, Biomolecular and Corrosion Engineering, College of Engineering and Polymer Science, The University of Akron, Akron, OH 44325, USA † Electronic supplementary information (ESI) available. See DOI:

Conjugated molecule based 2D perovskites for high-performance perovskite solar cells[†]

advantages of the high charge carrier mobility of conjugated molecules and the high stability of 2D perovskites are highly imperative to ultimately balance the efficiency and stability of PSCs with 2D/3D perovskite bilayer thin films.

In this work, we report efficient and stable PSCs with a 2D/3D perovskite bilayer thin film, where the 2D perovskite thin layer is created using an innovative conjugated aniline 3-phenyl-2-propen-1-amine (PPA) as the organic space cation. The (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ perovskite bilayer thin film (where MA is $CH_3NH_3^+$) possesses higher crystallinity and passivated trap states, leading to enhanced charge transport and suppressed charge carrier recombination compared to those of the 3D MAPbI₃ thin film. As a result, PSCs with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film exhibit a PCE of 21.98% and significantly boosted stability in an ambient atmosphere. Our results demonstrate that the incorporation of conjugated molecules as organic spacer cations to create a 2D perovskite on top of a 3D perovskite is an effective way to develop high-performance PSCs.

2. Experimental section

2.1 Materials

Gamma-butyrolactone (GBL, 99%), methylamine (MA) (33 wt% in absolute ethanol), anhydrous acetonitrile (ACN, 99.8%), poly [bis(4-phenyl)(2,4,6-trimethylphenyl)amine] (PTAA), dimethylformamide (DMF, anhydrous, 99.8%), dimethyl sulfoxide (DMSO, anhydrous, 99.9%), toluene (anhydrous, 99.8%), bathocuproine (BCP, 99.99%), aluminum (Al) and silver (Ag) slugs were purchased from Sigma Aldrich. Lead iodide (PbI₂, 99.9985% metals basis) was purchased from Alfa Aesar. C_{60} (99.95% carbon powder) was purchased from Purec60OliveOil. Methyl-ammonium iodide (MAI) was purchased from Greatcell Solar. All materials were used as received without any further treatment. 3-Phenyl-2-propen-1-amine (PPA) was synthesized in our laboratory. The details of the synthesis procedures and characterization of PPA are described in the ESI[†] (SI 1).

2.2 Preparation of the precursor solution

The MAPbI₃ **perovskite solution.** PbI₂ and MAI (molar ratio 1 : 1) were dissolved in GBL and stirred at 80 °C for over 2 hours (h) to form a 1.2 M solution. The solution was filtered into a vial and placed into an oil bath at 110 °C for several h until black crystals precipitated at the bottom of the vial. The black MAPbI₃ crystals were washed with isopropanol and dried three times. Then, a certain amount of MAPbI₃ crystals was placed in a vial, which was then sealed into a bottle containing methylamine solution and kept for over 2 h. Methylamine gas in the bottle diffused into the vial and reacted with the MAPbI₃ crystals, resulting in a liquid perovskite intermediate (MAPbI₃). Subsequently, MAPbI₃ crystals were dissolved into ACN to form a MAPbI₃ ACN solution.

The PPA solution. The PPA solution was prepared by dissolving the as-synthesized PPA into ACN with different concentrations.

2.3 Preparation and characterization of the perovskite thin film

The pre-cleaned quartz (or glass) substrates were treated by UV– ozone plasma for about 20 minutes (min). The MAPbI₃ thin film or (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film was prepared by the spin-cast method with a spin speed of 4000 RPM for 30 seconds (s) from the corresponding solution described above. After that, all of the thin films were thermally annealed at 100 °C for 10 min and then cooled down to room temperature (RT) naturally.

The X-ray diffraction (XRD) patterns were obtained by a Rigaku Smartlab. The UV-visible absorption spectra were characterized by a Lambda 900 UV-Vis-NIR spectrophotometer (PerkinElmer, Waltham, MA, USA). The photoluminescence (PL) spectra were obtained from a QuantaMaster 2361 (HORIBA). The scanning electron microscopy (SEM) images were obtained using a field emission scanning electron microscope (model JEOL-7401). The film thicknesses were measured using a Bruker DektakXT Stylus Profilometer with a scan rate of 0.03 mm s^{-1} .

2.4 Fabrication and characterization of the PSCs

The pre-cleaned ITO/glass substrates were treated by UV-ozone plasma for about 20 min, where ITO is indium tin oxide. Then, a ~20 nm PTAA thin film was spin-casted on the top of the ITO/ glass substrates with a spin speed of 6000 RPM for 30 s from 2 mg mL⁻¹ PTAA toluene solution, followed by thermal annealing at 100 °C for 10 min. After the PTAA coated substrates were cooled down to RT, either MAPbI₃ or (PPA)_x(MAPbI₃)_{1-x}/ MAPbI₃ thin films were prepared by the methods described above. Afterward, ~40 nm C₆₀ and ~8 nm BCP were sequentially thermally deposited on the top of either the MAPbI₃ thin film or the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film in a vacuum system with a base pressure of 4 × 10⁻⁶ Torr. The PSCs were completed by the thermal deposition of ~100 nm Al on the top of the BCP layer in a vacuum system. The device area was measured to be 0.043 cm².

The current density *versus* voltage (*J*–*V*) characteristics of the PSCs were tested by a Keithley model 2400 source unit. The light source was a Newport Air Mass 1.5 Global (AM1.5G) full spectrum simulator with a light intensity of 100 mW cm⁻², which was calibrated by utilizing a mono-silicon detector (with a KG-5 visible color filter) from the National Renewable Energy Laboratory to reduce the spectral mismatch. The external quantum efficiency (EQE) spectrum was obtained by a solar cell quantum efficiency measurement system (QEX10). The impedance spectroscopy (IS) was conducted using a HP 4194A impedance/gain-phase analyzer under illumination and in the dark, at the voltage close to the open-circuit voltage (V_{OC}) of the PSCs. The frequency was varied from 5 Hz to 105 Hz. Capacitance-voltage (C–V) testing was also performed using the same setup. The

transient photocurrent (TPC) measurement was done using a homemade setup in our laboratory.^{5,15,31,32}

3. Results and discussion

PPA, as shown in Fig. 1a, is a conjugated molecule used to create a discrete 2D (PPA)_x(MAPbI₃)_{1-x} thin layer on the top of 3D MAPbI₃ thin film to generate the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin films. Fig. 1b presents the UV-visible absorption spectra of the MAPbI₃ thin film and the $(PPA)_r(MAPbI_3)_{1-r}$ MAPbI₃ bilayer thin film. Due to the quantum confinement, a slightly blue-shifted absorption spectrum is observed from the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film compared to that of the MAPbI₃ thin film. Moreover, a blue-shifted PL is also observed from the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film (774 nm) compared to that (780 nm) from the MAPbI₃ thin film (Fig. 1c and d). In addition, an emission peak located at 722 nm observed for the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film indicates the existence of $(PPA)_x(MAPbI_3)_{1-x}$ perovskite due to multiple n values coexisting in the system. All of these results indicate that $(PPA)_x(MAPbI_3)_{1-x}$ is formed as a 2D perovskite structure.³³⁻³⁵ In addition, compared to 3D MAPbI₃, an obviously increased PL intensity is observed for the (PPA)_x(- $MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film (Fig. S1[†]), which indicates that the non-radiative recombination within the $(PPA)_r$ $MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film was significantly suppressed.

The XRD patterns of the MAPbI₃ thin film and the $(PPA)_x(-MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film are shown in Fig. 2a. The

H₂N

MAPbl

Front

Back

700

Wavelength (nm)

650

(a)

(c)

PL intensity (a.u.)

0.8

0.6

0.4

600

(110) and (220) peaks at 2θ of $\sim 14^{\circ}$ and $\sim 28^{\circ}$, respectively, demonstrate that both the MAPbI₃ thin film and the (PPA)_r(- $MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film possess the tetragonal (I4/ mcm) crystal structure.³⁶ However, a peak located at a 2θ of \sim 6.6°, corresponding to the (002) plane, is observed for the $(PPA)_{r}(MAPbI_{3})_{1-r}/MAPbI_{3}$ bilayer thin film, which further confirms that $(PPA)_x(MAPbI_3)_{1-x}$ is formed as a 2D perovskite structure.33-35 Fig. 2b shows the patterns of the (110) peaks for the MAPbI₃ thin film and the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film. It is found that the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film possesses a smaller full width at half maximum (FWHM) (0.201°) compared to that (0.309°) observed for the MAPbI₃ thin film, indicating that the $(PPA)_x(MAPbI_3)_{1-x}$ MAPbI₃ bilayer thin film exhibits greater crystallinity.³⁷ This greater crystallinity is attributed to the progressive trap healing at the grain boundaries and the passivated surface of the thin film.38,39

Fig. 2c and d present the SEM images of the MAPbI₃ thin film and the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film, respectively. It is found that patches of a new phase with bright grain spots are observed for the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film compared to the MAPbI₃ thin film. These bright grain spots originate from the lower electrical conductivity of the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film compared to that of the MAPbI₃ thin film. All of these characteristics further confirm that (PPA)_x(MAPbI₃)_{1-x} is indeed formed as a 2D perovskite structure.⁴⁰

To verify that the conjugated molecule, PPA, could facilitate charge transport, the charge carrier mobility of the

MAPbl

700

(PPA),(MAPbl₃),/MAPbl

Front

Back

650

Wavelength (nm)

722 nn

700

750

Wavelength (nm)

(PPA) (MAPbl.), /MAPb

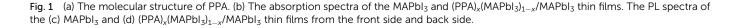
750

800

774 nm

800

850



850

(b) 0.8

Absorption (a.u.)

0.6

0.4

0.2

(d)

PL intensity (a.u.)

780 nm

800

750

600

0.8

0.6

0.4

0.2

600

650

850



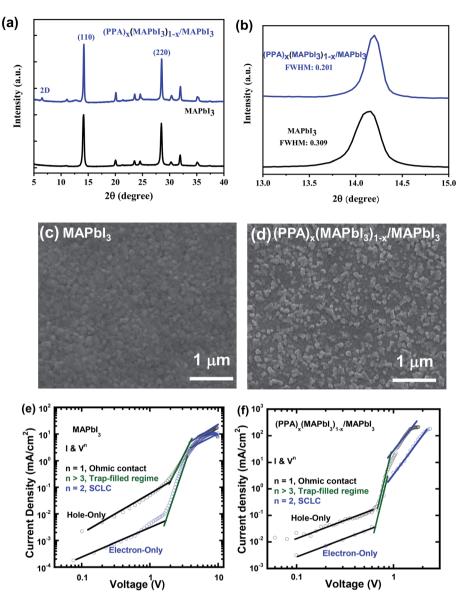


Fig. 2 (a) XRD patterns of the MAPbI₃ and (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ thin films and (b) magnified (110) peak of the XRD patterns. Top-view SEM images of the (c) MAPbI₃ and (d) (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ thin films, and the current density *versus* voltage characteristics of the diodes fabricated with the (e) MAPbI₃ and (f) (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ thin films, respectively.

 $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film is investigated through the characterization of both electron-only and holeonly diodes, based on the space charge limited current (SCLC) method, according to the Mott–Gurney law.⁴¹⁻⁴⁴ The electrononly diode, with a device structure of ITO/SnO₂/active layer/ C_{60}/Al , and the hole-only diode, with a device structure of ITO/ PEDOT:PSS/active layer/MoO₃/Ag, where the active layer is either the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film or the MAPbI₃ thin film, are fabricated and characterized. As shown in Fig. 2e and f, the *J*–*V* characteristics can be divided into the ohmic region ($J \propto V$) under the low bias and the SCLC region ($J \propto V^2$) under high bias. The *J*–*V* curve in the SCLC region could be well-fitted by the Mott–Gurney law: $J = \frac{9\varepsilon\varepsilon_0\mu V^2}{8L^2}$ (where μ is the charge carrier mobility, *V* is the external bias, *L* is the thickness of the perovskite thin film, ε_0 is the vacuum permittivity and ε is the dielectric constant for the perovskite thin film).⁴¹⁻⁴⁴ Based on the capacitance *versus* frequency (*C*-*V*) characteristics of the perovskite thin films (Fig. S2†), the ε values are calculated to be 26.6 and 25.4 for the (PPA)_x(-MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film and the MAPbI₃ thin film, respectively. Therefore, the charge carrier mobilities of the MAPbI₃ thin film are calculated to be 6.52×10^{-4} cm² V⁻¹ s⁻¹ (electron mobility) and 1.43×10^{-3} cm² V⁻¹ s⁻¹ (hole mobility). These values are consistent with the reported values.^{45,46} Furthermore, these charge carrier mobility values indicate that the charge transport is unbalanced ($\mu_e/\mu_h = 0.46$) within the MAPbI₃ thin film. The charge carrier mobilities for the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film are calculated to be 7.52×10^{-3} cm² V⁻¹ s⁻¹ (electron mobility) and 8.24×10^{-3}

cm² V⁻¹ s⁻¹ (hole mobility). Both the hole mobility and electron mobility of the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film are higher than those of the MAPbI₃ thin film. Such boosted charge carrier mobilities are attributed to the conjugated chain of PPA as compared with the insulating organic spacers.^{22–28} Moreover, these charge carrier mobility values indicate that the charge transport tends to be balanced ($\mu_e/\mu_h = 0.90$). As a result, an enhanced J_{SC} is expected to be observed from the PSCs with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film.

The photovoltaic properties of the $(PPA)_x(MAPbI_3)_{1-x}$ MAPbI₃ bilayer thin film are investigated through the characterization of the PSCs with a device structure of ITO/PTAA/ perovskite/C₆₀/BCP/Al, where ITO acts as the anode, PTAA acts as the hole extraction layer (HEL), C₆₀ is used as the electron extraction layer (EEL) and the hole blocking layer (HBL), BCP is used as another HBL and Al acts as the cathode. Fig. 3a presents the statistics of the PCEs of the PSCs with the (PPA)_r(- $MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin films with different PPA concentrations. The PCE values of the PSCs are increased and then decreased with the increased concentration of PPA. When the concentration of PPA is at 0.5%, the PSC with the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film exhibits the best PCE. The J-V characteristics of the PSCs with either the MAPbI₃ thin film or the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film (x = 0.5%)are shown in Fig. 3b. The PSC with the MAPbI₃ thin film exhibits a short-circuit current density (J_{SC}) of 21.41 mA cm⁻², a V_{OC} of 1.04 V and a fill factor (FF) of 78%, with a corresponding PCE of

17.37%. These device performance parameters are consistent with the reported values.⁴⁷ The PSC with the $(PPA)_x(MAPbI_3)_{1-x}$ MAPbI₃ bilayer thin film exhibits a J_{SC} of 25.92 mA cm⁻², a V_{OC} of 1.06 V, a FF of 80% and a corresponding PCE of 21.98%, which is approximately a 25% enhancement compared to that with the MAPbI₃ thin film. This boosted PCE is ascribed to the conjugated PPA organic spacer with better charge transport properties in comparison with insulating molecules such as butyl amine and benzene-based amines.¹⁹⁻²⁸ Fig. 3c shows the EQE spectra of the PSCs. The PSC with the $(PPA)_r(MAPbI_3)_{1-r}$ MAPbI₃ bilayer thin film exhibits an enhanced EQE value compared to that with the MAPbI₃ thin film. The integrated current densities are 20.89 mA $\rm cm^{-2}$ and 25.24 mA $\rm cm^{-2}$ for the PSC with the MAPbI₃ thin film and the PSC with the $(PPA)_x(MAPbI_3$ _{1-y}/MAPbI₃ bilayer thin film, respectively. These integrated current densities are in good agreement with the J_{SC} values obtained from the *I-V* characteristics (Fig. 3b).

The stability of the un-encapsulated PSC measured in the ambient atmosphere (25 °C and 30 \pm 10 humidity) is shown in Fig. 3d. The PSC with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film retains 50% of its initial PCEs after 1200 hours (h), whereas the PSC with the MAPbI₃ thin film shows a significant degradation after 100 h and more than 50% of the original PCE is degraded after 500 h. The conjugated long-chain cations of PPA could anchor on the surface of the perovskite grain boundary, which could passivate the trap states, resulting in a robust (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film which can

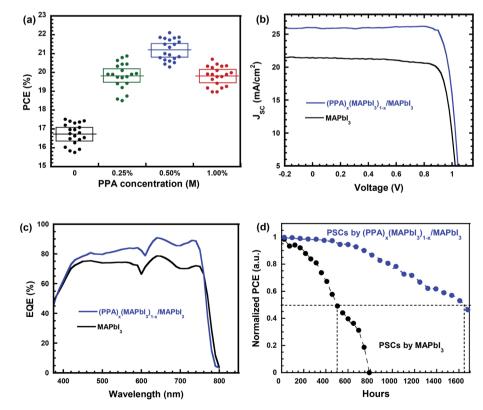


Fig. 3 (a) The statistics of the PCE of the PSCs with $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ thin films with different PPA concentrations. (b) The J-V characteristics and (c) EQE spectra of PSCs with either the MAPbI_3 or $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ thin films. (d) The stabilities of the PSCs with either the MAPbI_3 thin film or the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ thin film or the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ thin film.

withstand moisture and oxygen. In addition, the enhanced stability of the PSC is attributed to the pinhole-free thin film of the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer.

To understand the underlying physics of the enhanced J_{SC} , TPC measurements are carried out to probe the photogenerated charge transport rather than to just measure the photocurrent.³² Fig. 4a presents the TPC curves of the PSCs. As an external bias of -1.0 V is applied across the PSCs to minimize the charge carrier recombination, the charge carrier extraction time is estimated by extrapolating the photocurrent density to zero from the linear regime.³² Based on the normalized TPC curves, the charge carrier extraction times are estimated to be ~90 ns and ~70 ns for the PSC with the MAPbI₃ thin film and the PSC with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film, respectively. A short charge carrier extraction time indicates that an efficient charge extraction process takes place in solar cells.³² Thus, the PSC with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film exhibits a higher J_{SC} .

The light intensity-dependent $J_{\rm SC}$ and $V_{\rm OC}$ are investigated to visualize the charge carrier recombination loss mechanisms in the PSCs. As indicated in Fig. 4b, both PSCs follow the relationship of $V_{\rm OC} \propto S \ln (I)^{48}$ (where $S = nk_{\rm B}T/q$, $k_{\rm B}$ is the Boltzmann constant, T is the absolute temperature, q is the elementary charge and I is the light intensity). The $S = 1.56k_{\rm B}T/q$ observed from the PSC with the MAPbI₃ thin film indicates that both bimolecular charge carrier recombination and trapassisted charge carrier recombination occurred in the PSC; whereas the $S = 1.11k_{\rm B}T/q$ observed from the PSC with the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film indicates that the trap-assisted charge carrier recombination within PSCs is suppressed. Furthermore, based on $J_{SC} \propto I^{\alpha}$ (where *I* is the light intensity and α is the coefficient),⁴⁸ both PSCs exhibit a power-law dependence of J_{SC} on the light intensity. As $\alpha = 1$, all charge carriers are swept out before recombination. α of 0.83 and 0.94 are observed for the PSC with the MAPbI₃ thin film and the PSC with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film, respectively. A large α suggests that the bimolecular recombination is suppressed. Thus, the PSC with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film exhibit a boosted J_{SC} compared to that with the MAPbI₃ thin film.

IS is applied to investigate the charge transport and recombination processes within the PSCs.⁴⁹ As indicated in Fig. 4c, the charge carrier recombination resistances (R_{rec}) for the PSC with the MAPbI₃ thin film and the PSC with the $(PPA)_x(MAPbI_3)_{1-x}$ MAPbI₃ bilayer thin film, measured in the dark, are estimated to be ~440 Ω , and ~720 Ω , respectively. A high $R_{\rm rec}$ indicates that weak charge carrier recombination takes place in the PSC. Thus, the PSC with the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film exhibits a higher J_{SC} . The charge transfer resistance (R_{CT}) values are further calculated from the IS spectra at low frequencies, measured under white light illumination (Fig. 4c). The R_{CT} for the PSC with the $(PPA)_x(MAPbI_3)_{1-x}/MAPbI_3$ bilayer thin film is calculated to be ~80 Ω , whereas a $R_{\rm CT}$ of ~130 Ω is calculated for the PSC with the MAPbI₃ thin film. A small R_{CT} indicates that the charge transport properties of the PSC are boosted, thereby resulting in an enhanced J_{SC}.⁵⁰

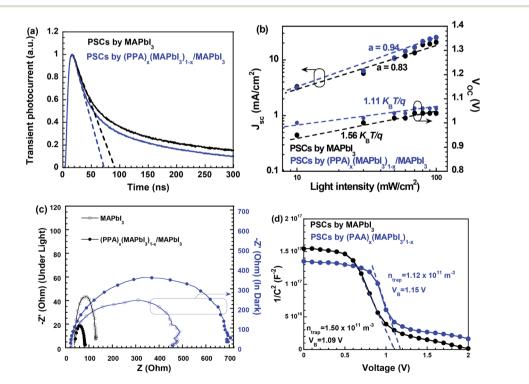


Fig. 4 (a) The normalized transient photocurrent (TPC) curve of the PSCs with either the MAPbl₃ thin film or the (PPA)_x(MAPbl₃)_{1-x}/MAPbl₃ thin film. (b) V_{OC} and J_{SC} versus light intensity of the PSCs with either the MAPbl₃ thin film or the (PPA)_x(MAPbl₃)_{1-x}/MAPbl₃ thin film. (c) Nyquist plots of the PSCs with either the MAPbl₃ thin film, measured in the dark, and (d) the Mott–Schottky analysis of the PSCs.

Mott–Schottky analysis, based on the *C*–*V* measurements, is further carried out to investigate the built-in potentials (*V*_{bi}) of the PSCs.⁵⁰ As shown in Fig. 4d, under the forward bias, the *V*_{bi} of the PSCs are extracted from $C^{-2} = \frac{2(V_{\rm bi} - V)}{q\varepsilon \varepsilon_0 A^2 n_{\rm trap}}^{48}$ (where ε is the dielectric constant, ε_0 is the vacuum permittivity and *A* is the active area) by extrapolating the linear fitting line to the intercept on the *x*-axis. It is found that a *V*_{bi} of ~1.15 V is observed for the PSC with the (PPA)_{*x*}(MAPbI₃)_{1-*x*}/MAPbI₃ bilayer thin film, whereas a *V*_{bi} of ~1.09 V is observed for the PSC with the MAPbI₃ thin film. Therefore, as expected, the PSC with the (PPA)_{*x*}(-MAPbI₃)_{1-*x*}/MAPbI₃ bilayer thin film exhibits a larger *V*_{OC} compared to that with the MAPbI₃ thin film.

4. Conclusions

In conclusion, an innovative conjugated aniline PPA to create a 2D (PPA)_x(MAPbI₃)_{1-x} thin layer and to further form the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film to develop efficient and stable perovskite solar cells was reported in this study. Systematic studies indicated that the (PPA)_x(MAPbI₃)_{1-x}/ MAPbI₃ bilayer thin film possessed higher crystallinity and passivated trap states, resulting in improved charge carrier transport and suppressed charge carrier recombination with respect to those of the MAPbI₃ thin film. As a result, the PSC with the (PPA)_x(MAPbI₃)_{1-x}/MAPbI₃ bilayer thin film exhibited a PCE of 21.98% and a significantly boosted stability in an ambient atmosphere. Our results suggested that the utilization of conjugated molecules as organic spacer cations to create 2D perovskites and further form 2D/3D perovskite bilayer thin films is an effective way to develop high-performance PSCs.

Conflicts of interest

There are no conflicts to declare.

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